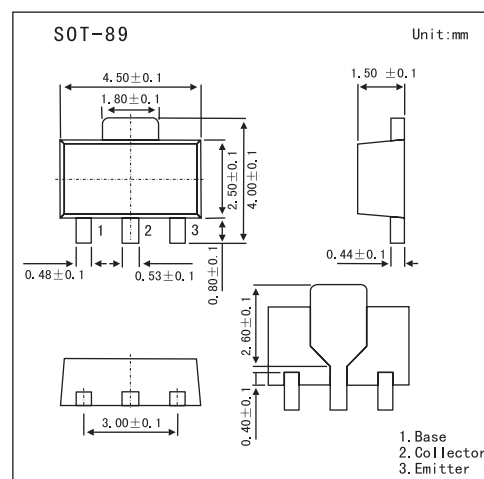


Triple Diffused NPN Transistor

KTC4372

■ Features

- High Voltage: $V_{CE0}=150V$
- High Transition Frequency: $f_T=120MHz$
- Small Flat Package

■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	200	V
Collector-Emitter Voltage	V_{CEO}	150	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	50	mA
Base Current	I_B	10	mA
Collector Power Dissipation	P_C	500	mW
	P_{C^*}	1	W
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to 150	$^\circ C$

* mounted on ceramic substrate (250mm²X0.8t)

■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector Cut-off Current	I_{CBO}	$V_{CB}=200V, I_E=0$			0.1	nA
Emitter-Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$			0.1	nA
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=10mA$	70		240	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=1mA$			0.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5V, I_C=30mA$			1.0	V
Transition Frequency	f_T	$V_{CE}=30V, I_C=10mA$		120		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$		3.5	5.0	pF

■ h_{FE} Classification

Marking	AO	AY
Rank	O	Y
Type	70~140	120~240